NSN 5961-01-037-8676 Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Plastic
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Height:
Between 0.080 inches and 0.105 inches
Overall Width:
Between 0.175 inches and 0.205 inches
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
32.0 regulator voltage
Current Rating Per Characteristic:
100.00 microamperes repetitive peak forward current
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector absolute
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
30131-release6315 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0